GH5C105D3A/GH5C105D3B

■ Features

- (1) With built-in OPIC* (TYP. 5MHz)
- (2) Enables to design compact pick-up thanks to compact package (Thickness: 4.8mm)
- (3) Voltage output type (External noise solution is unnecessary.)
- (4) Low current drive (Operating current: TYP. 18mA)
- (5) Maximum optical power output: 4.3mW
- (6) Wavelength: 780nm

*OPIC: (Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a lightdetecting element and signal-processing circuit integrated onto a single chip.

■ Model No.

- (1) GH5C105D3A....Dual power supply
- (2) GH5C105D3B....Single power supply

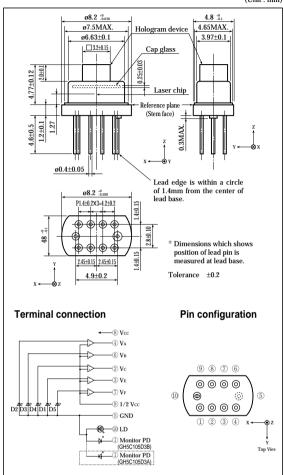
Applications

- (1) Audio CD drives
- (2) Video CD drives

Compact Size, Low Current Drive Hologram Laser for Audio/Video CD Player

Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

=	- Absolute maximum ratings						
	Parame	eter	Symbol	Rating	Unit		
*1	Optical power outpo	Рн	4.3	mW			
	Davianas valtara	Laser	VR	2	V		
	Reverse voltage	Monitor photodiode	V R	30	V		
	OPIC supply voltag	e	Vcc	6	V		
*2	Operating temperat	Topr	-10 to +60	.C			
*2	Storage temperatur	Tstg	-40 to +85	,C			
#3	Soldering temperat	ure	Tsold	260	°C		

^{*1} Output power from hologram laser

SHARP

(Tc-25°C)

^{*2} Case temperature

^{*3} At the position of 1.6mm or more from the lead base (Within 5s)

Electro-optical Characteristics

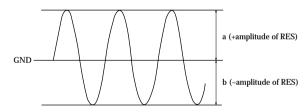
■ Electro-optical Characteristi	cs					(Vcc=5V	/, Tc=25°C)
Parameter	Symbol	Condi	tions	MIN.	TYP.	MAX.	Unit
*1 Focal offset	DEF	Vrf=0	.75V	-0.7	-	+0.7	μm
**2 Focal error symmetry	Bres	V _{RF} =0	.75V	-25	-	+25	%
*3 Radial error balance	Bres	V _{RF} =0	.75V	-25	-	+25	%
**4 RF output amplitude	Vrf	Рн=3.0)mW	0.53	1.2	2.1	V
*5 FEC output amplitude	VFES	V 0	751	0.2	0.5	0.7	v
*5 FES output amplitude	IFES	V _{RF} =0.75V		0.3	0.5	0.7	·
*6 DEC	Vres	V _{RF} =0.75V		0.12	0.21	0.29	v
*6 RES output amplitude	Ires						
Jitter GH5C105D3A	_	_		-	-	23	ns
Threshold current	Ith	_		-	13	18	mA
Operating current	Iop	P _H =2.7mW		-	18	22	mA
Operating voltage	Vop	Рн=2.7	7mW	-	1.8	2.2	V
Wavelength	λ_p	Po=3:	mW	770	780	795	nm
Output coment	Im	Рн=2.7mW,	GH5C105D3A	0.048	0.13	0.24	mA
Output current		V _R =15V	GH5C105D3B	0.021	0.6	0.11	IIIA
D::::		η _d 2mW I(3mW)-I(1mW)		-	0.65		mW/mA
Differential efficiency	ηd					-	
Interference pattern intensity GH5C105D3A	α	Po=2mW		-	-	0.95	-

Distance between FES=0 and jitter minimum point At the condition of FES sensitivity = $20\%/1\mu$ m

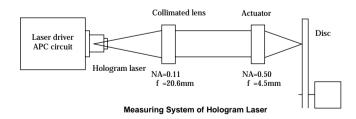
(a-b) / (a+b)

b (-amplitude of FES)





- **4 Amplitude of Va+Va+2Vc (focal servo ON, radial servo ON)
- *5 VB-VA (Focal vibration)
- *6 VE-VF (focal servo ON, radial servo OFF)



a-b 2×(a+b)

■ Electro-optical Characteristics of Laser Diode (Design Standard)

(Tc=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Emission	C	Parallel	S//	Po=3mW,	-25	-	+25	%
characteristics	Symmetry	Perpendicular	S⊥	into NA=0.11	-15	-	+15	%
Misalignment position			$\Delta \mathbf{x}$	_	-80	-	+80	μm
		Δy	_	-80	-	+80	μm	
			Δz	_	-80	-	+80	μm

■ Electrical Characteristics of Monitor Photodiode (Design Standard) (GH5C105D3A)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Sensitivity	S	V _R =15V	-	0.048	-	mA/mW
Dark current	I_{d}	V _R =15V	-	-	150	nA
Terminal capacitance	Ct	V _R =15V	-	3.5	-	pF

(GH5C105D3B)

 $(Tc=25^{\circ}C)$

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Sensitivity	S	$V_R=15V$	-	0.22	-	mA/mW
Dark current	\mathbf{I}_{d}	V _R =15V	-	-	150	nA
Terminal capacitance	Ct	V _R =15V	-	9	-	pF

^{*1} For hologram output power

■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*2 Segment
Supply voltage	Vcc		2.5	-	5.5	V	-
Supply current	Icc	Vcc=2.5V	2	5	10	mA	-
*3 Output off-set voltage	Vod	Vcc=2.5V, No light	-25	0	+25	mV	Va to F
Off-set voltage difference	ΔV od	vcc=2.5v, No light	-15	0	+15	mV	Va-VB, VE-VF
Response frequency	fcf	*4 Vcc=5V, -3dB	3	5	-	MHz	Va,VB,Vc
Response frequency	fcr	**4 Vcc=5V, -3dB	0.5	1	-	MHz	Ve,Vf
Temperature coefficient	ъ.	Ta= -20 to +70°C	1660	-	-	nnm /°C	Va,VB,Vc
of sensitivity	R _{plt}		1422	-	-	ppm/°C	Ve,Vf

^{®2} Applicable divisions correspond to pattern segment No.

D1	
D2	DA
D3	D4
D5	

Segment No.	Output
D 1	VE
D 2	VA
D 3	V _B
D 4	V c
D 5	V _F

^{*3} Difference from Vcc/2

^{*4} Output amplitude=0dB(input signal 100kHz)

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